

# SG2002/A

# 300mA, Low Power, Low Noise Low Dropout, Linear Regulators

## GENERAL DESCRIPTION

The SG2002/A series low-power, low-noise, low-dropout, CMOS linear voltage regulators operate from a 2.5V to 5.5V input and deliver up to 300mA. They are the perfect choice for low voltage, low power applications. An ultra low ground current (110 $\mu$ A at 300mA output) makes this part attractive for battery operated power systems. The SG2002/A series also offer ultra low dropout voltage (210mV at 300mA output) to prolong battery life in portable electronics. Systems requiring a quiet voltage source, such as RF applications, will benefit from the SG2002/A series' ultra low output noise (30 $\mu$ V<sub>RMS</sub>). An external noise bypass capacitor connected to the device's BP pin can further reduce the noise level.

The output voltage is preset to voltages in the range of 1.5V to 5.0V. Other features include a 10nA logic-controlled shutdown mode, foldback current limit and thermal shutdown protection.

Devices come in 5-pin SOT23 package.

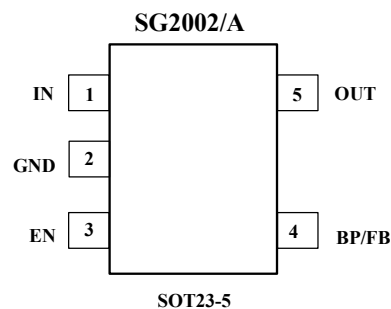
## FEATURES

- Low Output Noise: 30 $\mu$ V<sub>RMS</sub> typ(10Hz to 100KHz)
- Ultra-Low Dropout Voltage:  
210mV at 300mA output
- Low 77 $\mu$ A No-Load Supply Current
- Low 110 $\mu$ A Operating Supply Current  
at 300mA Output
- Thermal-Overload Protection
- Output Current Limit
- Preset Output Voltages ( $\pm$ 1.6% Accuracy)
- 10nA Logic-Controlled Shutdown
- Available in Multiple Output Voltage Versions  
Fixed Outputs of 1.5V, 1.8V, 2.5V, 2.8V, 2.85V,  
3.0V,3.3V, and 5.0V  
Adjustable Output from 1.5V to 5.0V

## APPLICATIONS

Cellular Telephones  
Cordless Telephones  
PHS Telephones  
PCMCIA Cards  
Modems  
MP3 Player  
Hand-Held Instruments  
Palmtop Computers  
Electronic Planners  
Portable/Battery-Powered Equipment

## PIN CONFIGURATIONS (TOP VIEW)



## ORDERING INFORMATION

| MODEL       | V <sub>OUT</sub> (V) | PIN-PACKAGE | SPECIFIED TEMPERATURE RANGE | ORDERING NUMBER   | PACKAGE MARKING | PACKAGE OPTION      |
|-------------|----------------------|-------------|-----------------------------|-------------------|-----------------|---------------------|
| SG2002-1.5  | 1.5V                 | SOT23-5     | - 40°C to +125°C            | SG2002-1.5XN5/TR  | X215            | Tape and Reel, 3000 |
| SG2002-1.8  | 1.8V                 | SOT23-5     | - 40°C to +125°C            | SG2002-1.8XN5/TR  | X218            | Tape and Reel, 3000 |
| SG2002-2.5  | 2.5V                 | SOT23-5     | - 40°C to +125°C            | SG2002-2.5XN5/TR  | X225            | Tape and Reel, 3000 |
| SG2002-2.8  | 2.8V                 | SOT23-5     | - 40°C to +125°C            | SG2002-2.8XN5/TR  | X228            | Tape and Reel, 3000 |
| SG2002-2.85 | 2.85V                | SOT23-5     | - 40°C to +125°C            | SG2002-2.85XN5/TR | X22J            | Tape and Reel, 3000 |
| SG2002-3.0  | 3.0V                 | SOT23-5     | - 40°C to +125°C            | SG2002-3.0XN5/TR  | X230            | Tape and Reel, 3000 |
| SG2002-3.3  | 3.3V                 | SOT23-5     | - 40°C to +125°C            | SG2002-3.3XN5/TR  | X233            | Tape and Reel, 3000 |
| SG2002-5.0  | 5.0V                 | SOT23-5     | - 40°C to +125°C            | SG2002-5.0XN5/TR  | X250            | Tape and Reel, 3000 |
| SG2002A     | adjustable           | SOT23-5     | - 40°C to +125°C            | SG2002-XN5/TR     | X2AA            | Tape and Reel, 3000 |

## ABSOLUTE MAXIMUM RATINGS

IN to GND..... - 0.3V to +6V  
 Output Short-Circuit Duration .....Infinite  
 EN to GND..... - 0.3V to +6V  
 OUT, BP/FB to GND.....- 0.3V to (V<sub>IN</sub> + 0.3V)  
 Power Dissipation, P<sub>D</sub> @ T<sub>A</sub> = 25°C  
 SOT23-5 .....0.4W  
 Package Thermal Resistance  
 SOT23-5, θ<sub>JA</sub>..... 250°C/W

Operating Temperature Range.....- 40°C to +125°C  
 Junction Temperature.....+150°C  
 Storage Temperature.....- 65°C to +150°C  
 Lead Temperature (soldering, 10s).....260°C  
 ESD Susceptibility  
 HBM.....7000V  
 MM.....400V

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## PIN DESCRIPTION

| PIN | NAME | FUNCTION  |
|-----|------|---|
| 1   | IN   | Regulator Input. Supply voltage can range from 2.5V to 5.5V. Bypass with a 1μF capacitor to GND.  |
| 2   | GND  | Ground.   |
| 3   | EN   | Shutdown Input. A logic low reduces the supply current to 10nA. Connect to IN for normal operation.                                     |
| 4   | BP   | Reference-Noise Bypass(fixed voltage version only). Bypass with a low-leakage 0.01μF ceramic capacitor for reduced noise at the output. |
| 4   | FB   | Adjustable voltage version only — this is used to set the output voltage of the device.   |
| 5   | OUT  | Regulator Output.   |

# ELECTRICAL CHARACTERISTICS

( $V_{IN} = V_{OUT(NOMINAL)} + 0.5V$  or  $2.5V$  (whichever is greater),  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

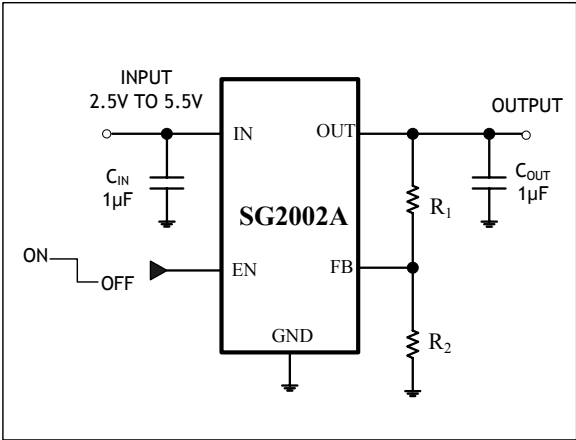
| PARAMETER                    | SYMBOL            | CONDITIONS   | MIN                   | TYP    | MAX   | UNITS       |         |
|------------------------------|-------------------|--|-----------------------|--------|-------|-------------|---------|
| Input Voltage                | $V_{IN}$          |  | 2.5                   |        | 5.5   | V           |         |
| Output Voltage Accuracy      |                   | $I_{OUT} = 0.1mA, V_{OUT} \geq 2.5V, T_A = +25^{\circ}C$                                   | -1.6                  |        | 1.6   | %           |         |
|                              |                   | $I_{OUT} = 0.1mA$ to $300mA, V_{OUT} \geq 2.5V$<br>$T_A = 0^{\circ}C$ to $+70^{\circ}C$    |                       |        | 2.3   |             |         |
|                              |                   | $I_{OUT} = 0.1mA$ to $300mA, V_{OUT} \geq 2.5V$<br>$T_A = -40^{\circ}C$ to $+125^{\circ}C$ |                       |        | 2.7   |             |         |
|                              |                   | $I_{OUT} = 0.1mA$ to $300mA, V_{OUT} < 2.5V$<br>$T_A = -40^{\circ}C$ to $+125^{\circ}C$    |                       |        | 2.9   |             |         |
| Maximum Output Current       |                   |  | 300                   |        |       | mA          |         |
| Current Limit                | $I_{LIM}$         |  | 310                   | 750    |       | mA          |         |
| Ground Pin Current           | $I_Q$             | No load, $EN = 2V$   | $V_{OUT} \leq 3.3V$   |        | 77    | 130         | $\mu A$ |
|                              |                   |  | $V_{OUT} > 3.3V$      |        | 77    | 145         |         |
|                              |                   | $I_{OUT} = 300mA, EN = 2V$   |                       |        | 110   |             |         |
| Dropout Voltage (Note1)      |                   | $I_{OUT} = 1mA$  |                       | 0.8    |       | mV          |         |
|                              |                   | $I_{OUT} = 300mA$  |                       | 210    | 340   |             |         |
| Line Regulation              | $\Delta V_{LNR}$  | $V_{IN} = 2.5V$ or $(V_{OUT} + 0.1V)$ to $5.5V$ ,<br>$I_{OUT} = 1mA$                       |                       | 0.004  | 0.15  | %/V         |         |
| Load Regulation              | $\Delta V_{LDR}$  | $I_{OUT} = 0.1mA$ to $300mA, C_{OUT} = 1\mu F$   |                       | 0.0005 | 0.002 | %/mA        |         |
| Output Voltage Noise         | $e_n$             | $f = 10Hz$ to $100KHz, C_{BP} = 0.01\mu F$ ,<br>$C_{OUT} = 10\mu F$                        |                       | 30     |       | $\mu VRMS$  |         |
| Power Supply Rejection Rate  | PSRR              | $C_{BP} = 0.1\mu F, I_{LOAD} = 50mA$ ,<br>$C_{OUT} = 1\mu F$                               | $f = 100Hz$ ,         |        | 74    |             | dB      |
|                              |                   |  | $f = 1KHz$ ,          |        | 54    |             | dB      |
| <b>SHUTDOWN</b>              |                   |  |                       |        |       |             |         |
| EN Input Threshold           | $V_{IH}$          | $V_{IN} = 2.5V$ to $5.5V$  | 2.0                   |        |       | V           |         |
|                              | $V_{IL}$          |  |                       |        | 0.4   |             |         |
| EN Input Bias Current        | $I_{B(SHDN)}$     | $EN = 0V$ and $EN = 5.5V$  | $T_A = +25^{\circ}C$  |        | 0.01  | 1           | $\mu A$ |
|                              |                   |  | $T_A = +125^{\circ}C$ |        | 0.01  |             |         |
| Shutdown Supply Current      | $I_{Q(SHDN)}$     | $EN = 0.4V$  | $T_A = +25^{\circ}C$  |        | 0.01  | 1           | $\mu A$ |
|                              |                   |  | $T_A = +125^{\circ}C$ |        | 0.01  |             |         |
| Shutdown Exit Delay(Note2)   |                   | $C_{BP} = 0.01\mu F$<br>$C_{OUT} = 1\mu F, No\ load$                                       | $T_A = +25^{\circ}C$  |        | 30    | $\mu s$     |         |
| <b>THERMAL PROTECTION</b>    |                   |  |                       |        |       |             |         |
| Thermal Shutdown Temperature | $T_{SHDN}$        |  |                       | 160    |       | $^{\circ}C$ |         |
| Thermal Shutdown Hysteresis  | $\Delta T_{SHDN}$ |  |                       | 15     |       | $^{\circ}C$ |         |

Specifications subject to change without notice.

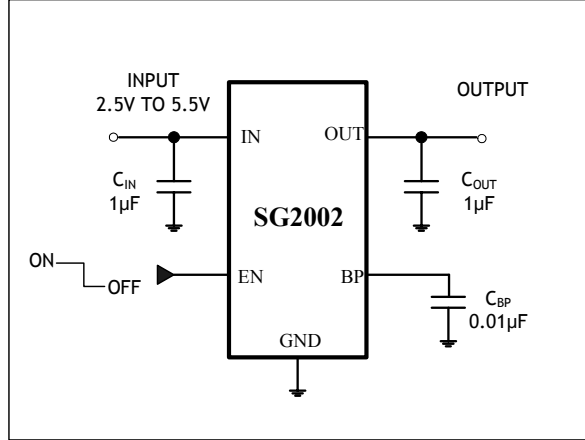
**Note 1:** The dropout voltage is defined as  $V_{IN} - V_{OUT}$ , when  $V_{OUT}$  is 100mV below the value of  $V_{OUT}$  for  $V_{IN} = V_{OUT} + 0.5V$ . (Only applicable for  $V_{OUT} = +2.5V$  to  $+5.0V$ .)

**Note 2:** Time needed for  $V_{OUT}$  to reach 95% of final value.

# TYPICAL OPERATION CIRCUIT



Adjustable Voltage Version



Fixed Voltage Version

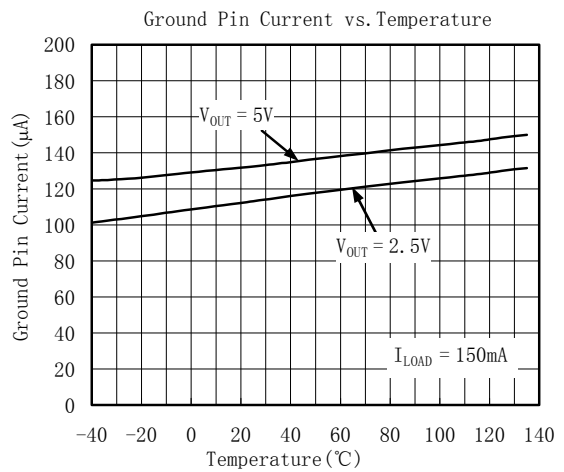
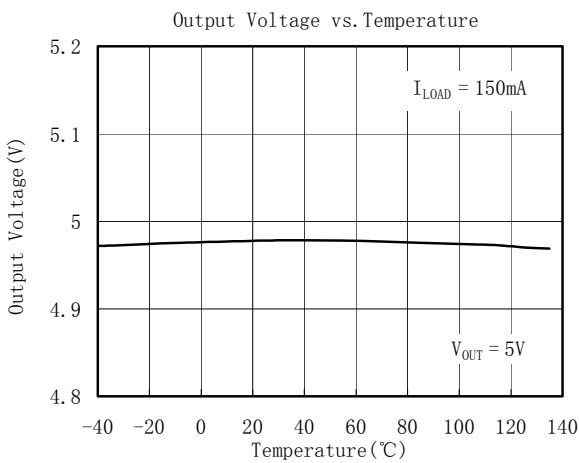
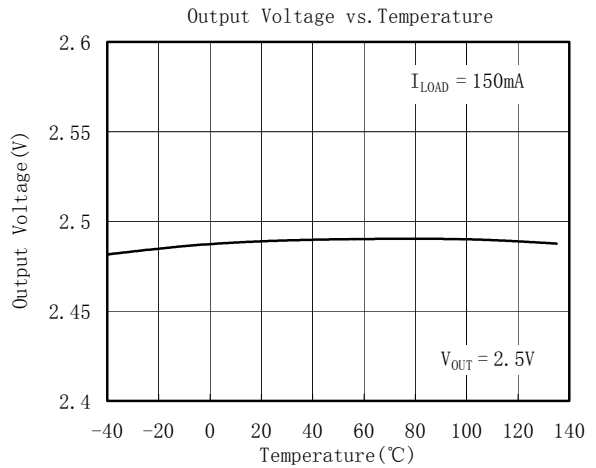
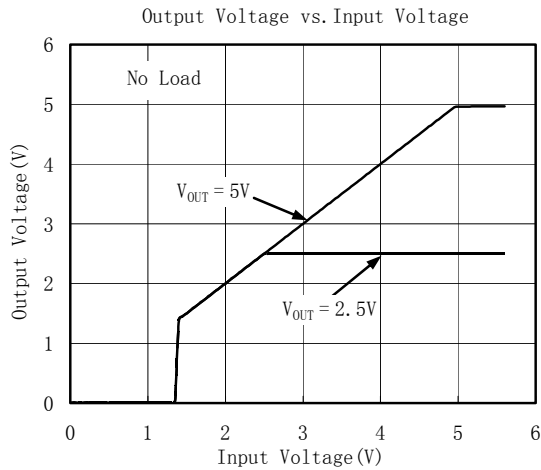
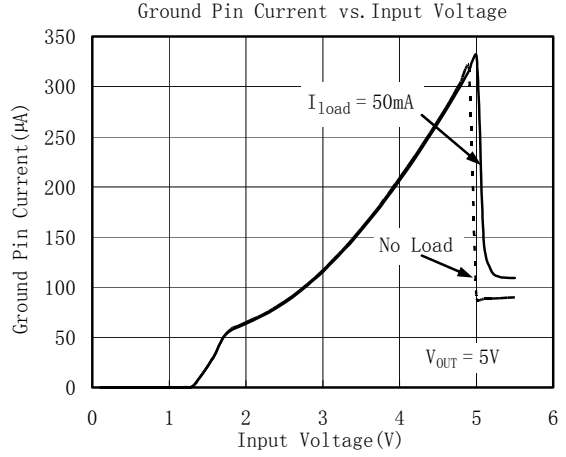
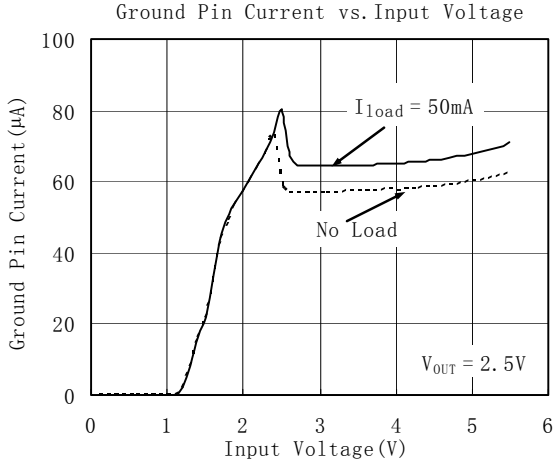
## Standard 1% Resistor Values for Common Output Voltages of Adjustable Voltage Version

| V <sub>OUT</sub> (V) | R <sub>1</sub> (kΩ) | R <sub>2</sub> (kΩ) |
|----------------------|---------------------|---------------------|
| 1.5                  | 13                  | 61.9                |
| 1.8                  | 28                  | 61.9                |
| 2.5                  | 63.4                | 61.9                |
| 2.8                  | 78.7                | 61.9                |
| 2.85                 | 80.6                | 61.9                |
| 3.0                  | 88.7                | 61.9                |
| 3.3                  | 95.3                | 57.6                |
| 5.0                  | 187                 | 61.9                |

Note:  $V_{OUT} = (R_1 + R_2) / R_2 \times 1.2395$

# TYPICAL OPERATING CHARACTERISTICS

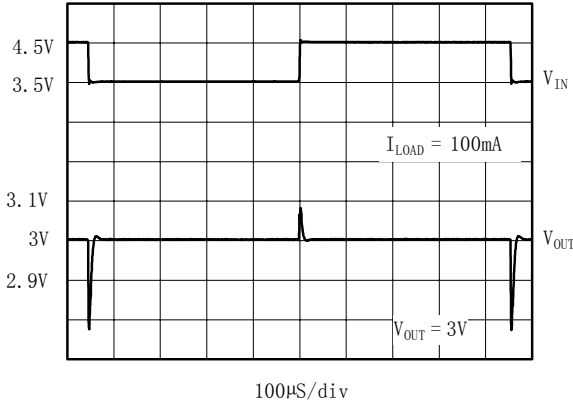
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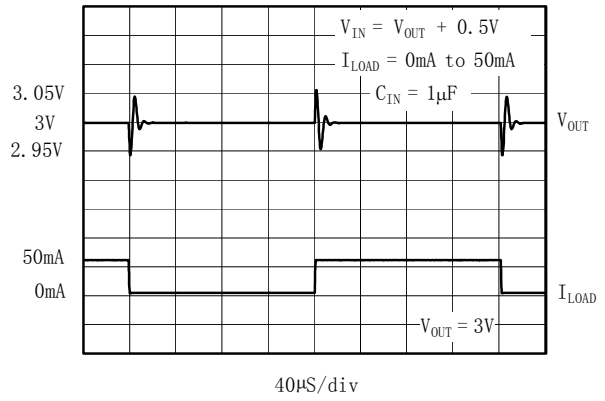
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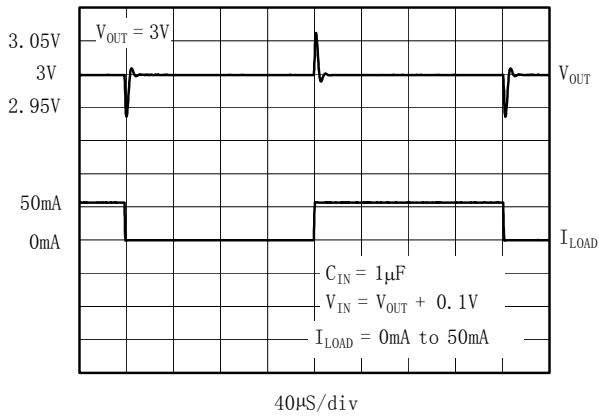
Line-Transient Response



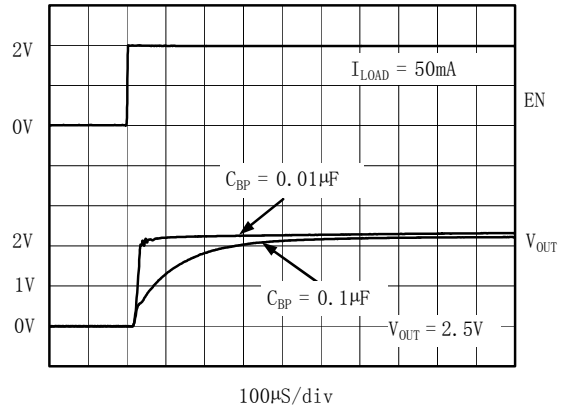
Load-Transient Response



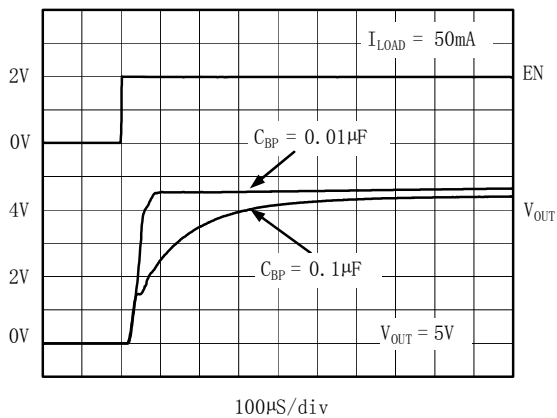
Load-Transient Response Near Dropout



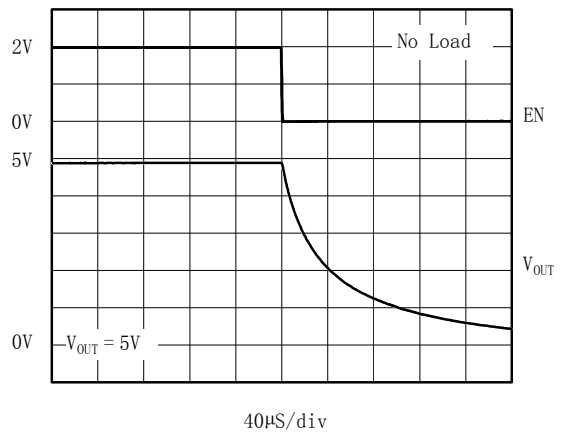
Shutdown Exit Delay



Shutdown Exit Delay

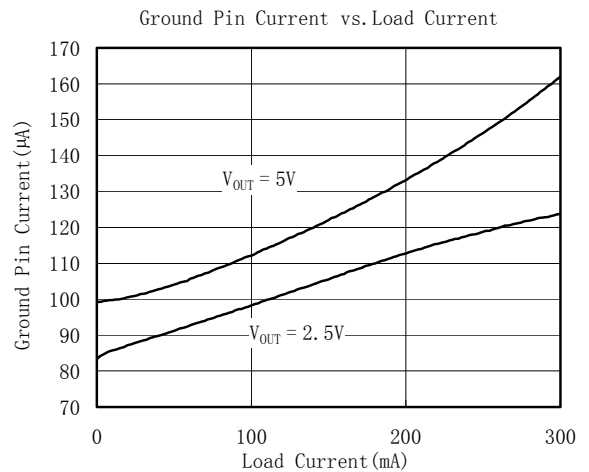
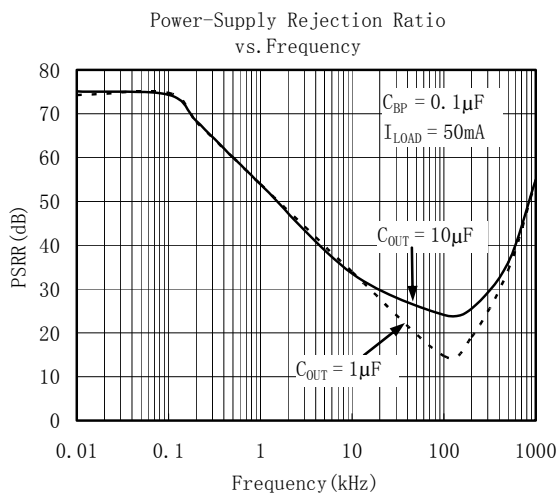
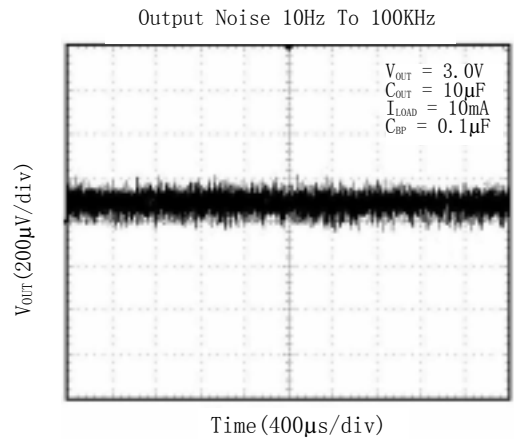
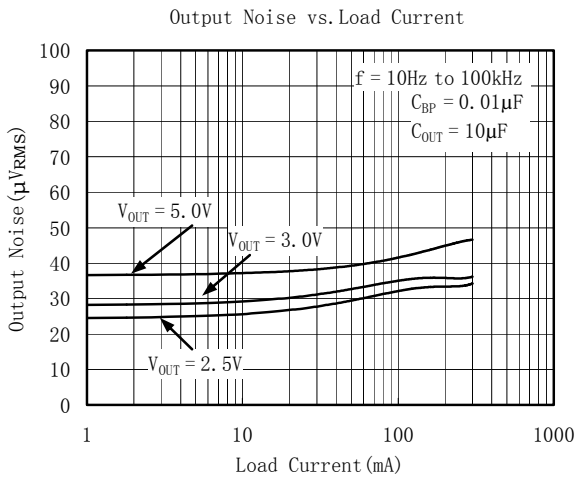
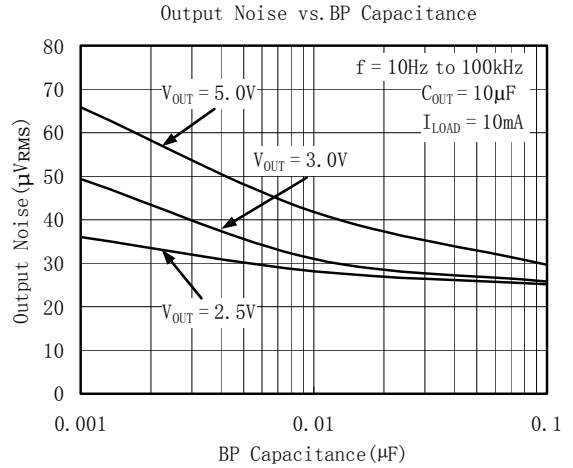
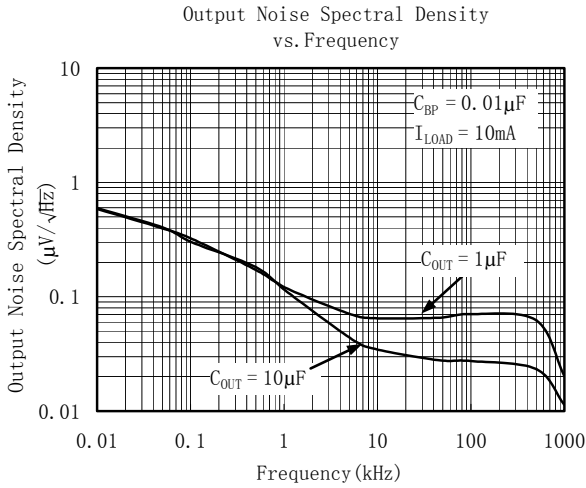


Entering Shutdown



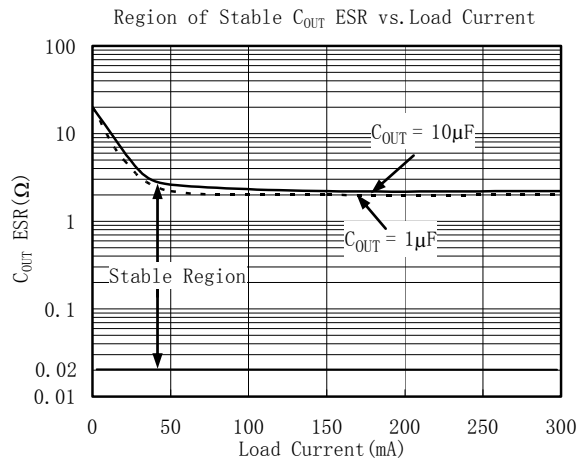
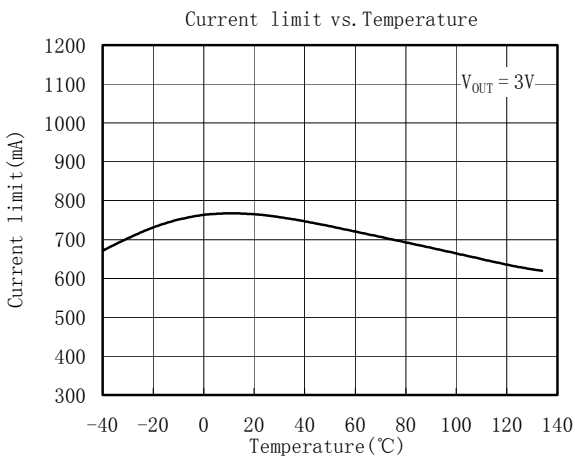
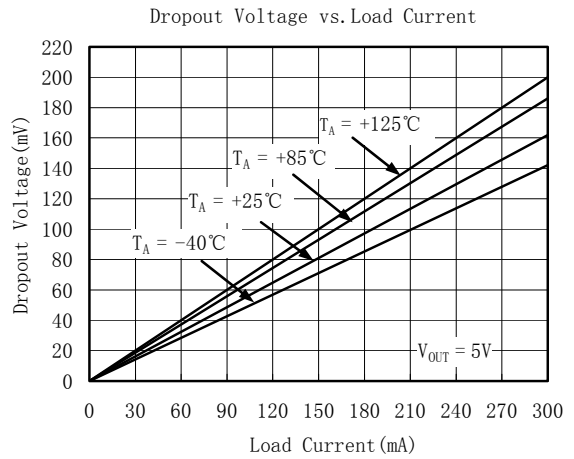
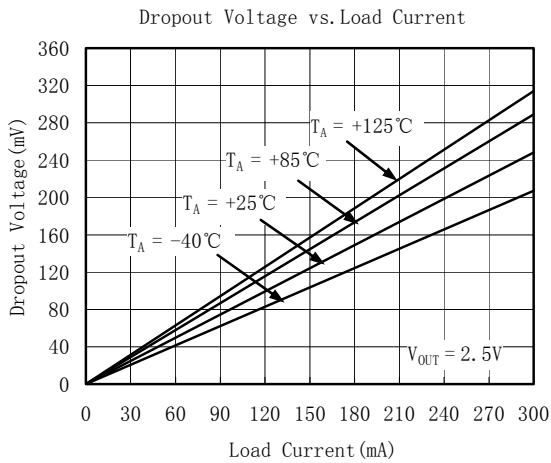
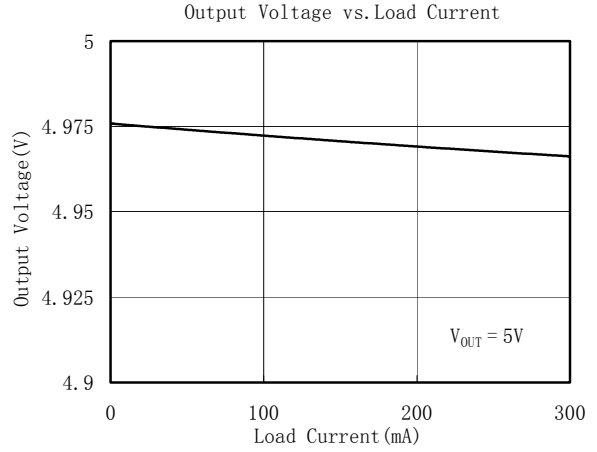
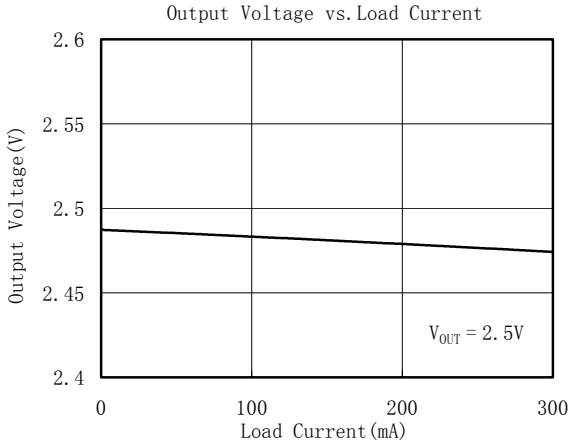
# TYPICAL OPERATING CHARACTERISTICS

$V_{IN} = V_{OUT(NOMINAL)} + 0.5V$  or  $2.5V$  (whichever is greater),  $C_{IN} = 1\mu F$ ,  $C_{OUT} = 1\mu F$ ,  $C_{BP} = 0.01\mu F$ ,  $T_A = +25^\circ C$ , unless otherwise noted.



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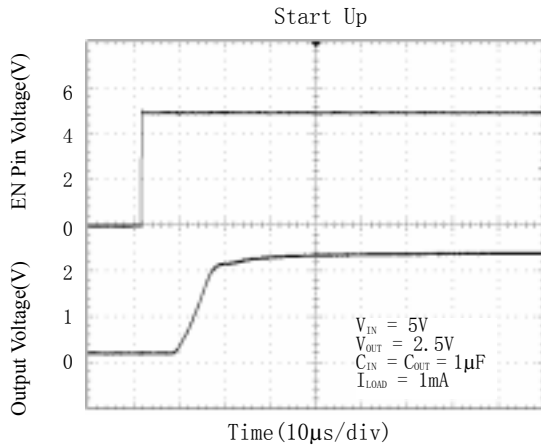
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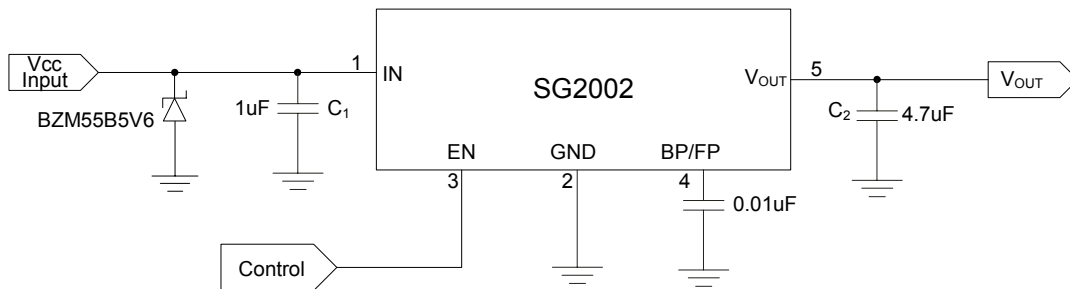
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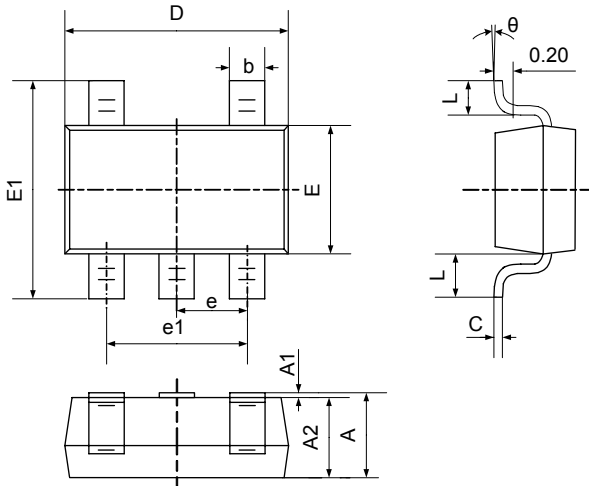
## Application Notes

When LDO is used in handheld products, Attention must be paid to voltage spike which would damage SG2002. In such applications, voltage spike will be generated at charger interface and  $V_{BUS}$  pin of USB interface when charger adapters and USB equipments are hot-inserted. Besides this, handheld products will be tested on the production line on the condition of no battery. Test Engineer will apply power from the connector pin which connects with positive pole of the battery. When external power supply is turned on suddenly, the voltage spike will be generated at the battery connector. The voltage spike will be very high, it always exceeds the absolute maximum input voltage (6.0V) of LDO. In order to get robust design. Design Engineer needs to clear up this voltage spike. Zener diode is a cheap and effective solution to eliminate such voltage spike. For example, BZM55B5V6 is a 5.6V small package Zener diode which can be used to remove voltage spike in cell phone design. The schematic is shown in below:



# PACKAGE OUTLINE DIMENSIONS

## SOT23-5



| Symbol | Dimensions<br>In Millimeters |       | Dimensions<br>In Inches |       |
|--------|------------------------------|-------|-------------------------|-------|
|        | Min                          | Max   | Min                     | Max   |
| A      | 1.050                        | 1.250 | 0.041                   | 0.049 |
| A1     | 0.000                        | 0.100 | 0.000                   | 0.004 |
| A2     | 1.050                        | 1.150 | 0.041                   | 0.045 |
| b      | 0.300                        | 0.400 | 0.012                   | 0.016 |
| c      | 0.100                        | 0.200 | 0.004                   | 0.008 |
| D      | 2.820                        | 3.020 | 0.111                   | 0.119 |
| E      | 1.500                        | 1.700 | 0.059                   | 0.067 |
| E1     | 2.650                        | 2.950 | 0.104                   | 0.116 |
| e      | 0.950TYP                     |       | 0.037TYP                |       |
| e1     | 1.800                        | 2.000 | 0.071                   | 0.079 |
| L      | 0.700REF                     |       | 0.028REF                |       |
| L1     | 0.300                        | 0.600 | 0.012                   | 0.024 |
| theta  | 0°                           | 8°    | 0°                      | 8°    |

## REVISION HISTORY

| Location  | Page |
|---|------|
| 9/05— Data Sheet changed from preliminary to REV. A |      |
| 12/06— Data Sheet changed from REV. A to REV. B     |      |
| Changed to ABSOLUTE MAXIMUM RATINGS .....           | 2    |
| Added Application Notes .....                       | 9    |

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